

**MICROCHIP****25AA160A/B, 25LC160A/B**

16K SPI Bus Serial EEPROM

Device Selection Table

Part Number	Vcc Range	Page Size	Temp. Ranges	Packages
25LC160A	2.5-5.5V	16 Byte	I,E	P, SN, ST, MS
25AA160A	1.8-5.5V	16 Byte	I	P, SN, ST, MS
25LC160B	2.5-5.5V	32 Byte	I,E	P, SN, ST, MS
25AA160B	1.8-5.5V	32 Byte	I	P, SN, ST, MS

Features:

- Max. Clock 10 MHz
- Low-Power CMOS Technology
- 2048 x 8-bit Organization
- 16-Byte Page ('A' version devices)
- 32-Byte Page ('B' version devices)
- Write Cycle Time: 5 ms max.
- Self-Timed Erase and Write Cycles
- Block Write Protection:
 - Protect none, 1/4, 1/2 or all of array
- Built-In Write Protection:
 - Power-on/off data protection circuitry
 - Write enable latch
 - Write-protect pin
- Sequential Read
- High Reliability:
 - Endurance: 1,000,000 erase/write cycles
 - Data retention: > 200 years
 - ESD protection: > 4000V
- Temperature Ranges Supported:
 - Industrial (I): -40°C to +85°C
 - Automotive (E): -40°C to +125°C
- Pb-Free and RoHS Compliant

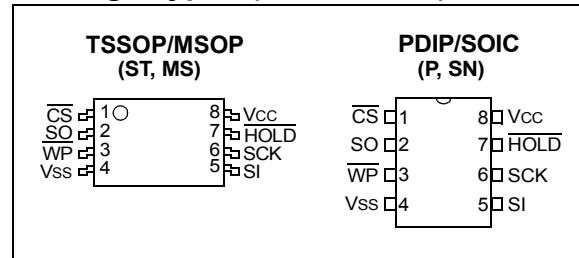
Description:

The Microchip Technology Inc. 25AA160A/B, 25LC160A/B (25XX160A/B*) are 16 Kbit Serial Electrically Erasable PROMs. The memory is accessed via a simple Serial Peripheral Interface (SPI) compatible serial bus. The bus signals required are a clock input (SCK) plus separate data in (SI) and data out (SO) lines. Access to the device is controlled through a Chip Select (CS) input.

Communication to the device can be paused via the hold pin (HOLD). While the device is paused, transitions on its inputs will be ignored, with the exception of Chip Select, allowing the host to service higher priority interrupts.

The 25XX160A/B is available in standard Pb-free packages including 8-lead PDIP and SOIC, and advanced packaging including 8-lead MSOP, and 8-lead TSSOP.

Package Types (not to scale)



Pin Function Table

Name	Function
CS	Chip Select Input
SO	Serial Data Output
WP	Write-Protect
Vss	Ground
SI	Serial Data Input
SCK	Serial Clock Input
HOLD	Hold Input
Vcc	Supply Voltage

*25XX160A/B is used in this document as a generic part number for the 25AA160A/B, 25LC160A/B devices.

25XX160A/B

1.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings^(†)

VCC.....	7.0V
All inputs and outputs w.r.t. Vss	-0.6V to Vcc +1.0V
Storage temperature	-65°C to 150°C
Ambient temperature under bias.....	-40°C to 125°C
ESD protection on all pins.....	4 kV

† NOTICE: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operational listings of this specification is not implied. Exposure to maximum rating conditions for an extended period of time may affect device reliability.

TABLE 1-1: DC CHARACTERISTICS

DC CHARACTERISTICS			Industrial (I): Automotive (E):		TAMB = -40°C to +85°C TAMB = -40°C to +125°C	Vcc = 1.8V to 5.5V Vcc = 2.5V to 5.5V
Param. No.	Sym.	Characteristic	Min.	Max.	Units	Test Conditions
D001	VIH1	High-level input voltage	2.0	VCC +1	V	VCC ≥ 2.7V (Note)
D002	VIH2		0.7 VCC	VCC +1	V	VCC < 2.7V (Note)
D003	VIL1	Low-level input voltage	-0.3	0.8	V	VCC ≥ 2.7V (Note)
D004	VIL2		-0.3	0.2 VCC	V	VCC < 2.7V (Note)
D005	VOL	Low-level output voltage	—	0.4	V	IOL = 2.1 mA
D006	VOL		—	0.2	V	IOL = 1.0 mA, VCC < 2.5V
D007	VOH	High-level output voltage	VCC -0.5	—	V	IOH = -400 μA
D008	ILI	Input leakage current	—	±1	μA	CS = VCC, VIN = VSS TO VCC
D009	ILO	Output leakage current	—	±1	μA	CS = VCC, VOUT = VSS TO VCC
D010	CINT	Internal Capacitance (all inputs and outputs)	—	7	pF	TAMB = 25°C, CLK = 1.0 MHz, VCC = 5.0V (Note)
D011	Icc Read	Operating Current	—	6	mA	VCC = 5.5V; FCLK = 10.0 MHz; SO = Open
			—	2.5	mA	VCC = 2.5V; FCLK = 5.0 MHz; SO = Open
D012	Icc Write		—	3	mA	VCC = 5.5V
D013	Iccs	Standby Current	—	5	μA	CS = VCC = 5.5V, Inputs tied to VCC or VSS, TAMB = -40°C TO +125°C
			—	1	μA	CS = VCC = 2.5V, Inputs tied to VCC or VSS, TAMB = -40°C TO +85°C

Note: This parameter is periodically sampled and not 100% tested.

TABLE 1-2: AC CHARACTERISTICS

AC CHARACTERISTICS			Industrial (I): TAMB = -40°C to +85°C VCC = 1.8V to 5.5V Automotive (E): TAMB = -40°C to +125°C VCC = 2.5V to 5.5V			
Param. No.	Sym.	Characteristic	Min.	Max.	Units	Test Conditions
1	FCLK	Clock Frequency	—	10	MHz	4.5V ≤ VCC ≤ 5.5V
			—	5	MHz	2.5V ≤ VCC < 4.5V
			—	3	MHz	1.8V ≤ VCC < 2.5V
2	Tcss	CS Setup Time	50	—	ns	4.5V ≤ VCC ≤ 5.5V
			100	—	ns	2.5V ≤ VCC < 4.5V
			150	—	ns	1.8V ≤ VCC < 2.5V
3	Tcsh	CS Hold Time	100	—	ns	4.5V ≤ VCC ≤ 5.5V
			200	—	ns	2.5V ≤ VCC < 4.5V
			250	—	ns	1.8V ≤ VCC < 2.5V
4	Tcsd	CS Disable Time	50	—	ns	—
5	Ts _u	Data Setup Time	10	—	ns	4.5V ≤ VCC ≤ 5.5V
			20	—	ns	2.5V ≤ VCC < 4.5V
			30	—	ns	1.8V ≤ VCC < 2.5V
6	THD	Data Hold Time	20	—	ns	4.5V ≤ VCC ≤ 5.5V
			40	—	ns	2.5V ≤ VCC < 4.5V
			50	—	ns	1.8V ≤ VCC < 2.5V
7	TR	CLK Rise Time	—	500	ns	(Note 1)
8	TF	CLK Fall Time	—	500	ns	(Note 1)
9	THI	Clock High Time	50	—	ns	4.5V ≤ VCC ≤ 5.5V
			100	—	ns	2.5V ≤ VCC < 4.5V
			150	—	ns	1.8V ≤ VCC < 2.5V
10	TLO	Clock Low Time	50	—	ns	4.5V ≤ VCC ≤ 5.5V
			100	—	ns	2.5V ≤ VCC < 4.5V
			150	—	ns	1.8V ≤ VCC < 2.5V
11	Tcld	Clock Delay Time	50	—	ns	—
12	Tcle	Clock Enable Time	50	—	ns	—
13	Tv	Output Valid from Clock Low	—	50	ns	4.5V ≤ VCC ≤ 5.5V
			—	100	ns	2.5V ≤ VCC < 4.5V
			—	160	ns	1.8V ≤ VCC < 2.5V
14	Tho	Output Hold Time	0	—	ns	(Note 1)
15	Tdis	Output Disable Time	—	40	ns	4.5V ≤ VCC ≤ 5.5V (Note 1)
			—	80	ns	2.5V ≤ VCC ≤ 4.5V (Note 1)
			—	160	ns	1.8V ≤ VCC ≤ 2.5V (Note 1)
16	Ths	HOLD Setup Time	20	—	ns	4.5V ≤ VCC ≤ 5.5V
			40	—	ns	2.5V ≤ VCC < 4.5V
			80	—	ns	1.8V ≤ VCC < 2.5V

Note 1: This parameter is periodically sampled and not 100% tested.

2: This parameter is not tested but ensured by characterization. For endurance estimates in a specific application, please consult the Total Endurance™ Model which can be obtained from our web site:

3: T_{WC} begins on the rising edge of CS after a valid write sequence and ends when the internal write cycle is complete.

25XX160A/B

TABLE 1-2: AC CHARACTERISTICS (CONTINUED)

AC CHARACTERISTICS			Industrial (I): TAMB = -40°C to +85°C Vcc = 1.8V to 5.5V Automotive (E): TAMB = -40°C to +125°C Vcc = 2.5V to 5.5V			
Param. No.	Sym.	Characteristic	Min.	Max.	Units	Test Conditions
17	THH	HOLD Hold Time	20	—	ns	4.5V ≤ Vcc ≤ 5.5V
			40	—	ns	2.5V ≤ Vcc < 4.5V
			80	—	ns	1.8V ≤ Vcc < 2.5V
18	THZ	HOLD Low to Output High-Z	30	—	ns	4.5V ≤ Vcc ≤ 5.5V (Note 1)
			60	—	ns	2.5V ≤ Vcc < 4.5V (Note 1)
			160	—	ns	1.8V ≤ Vcc < 2.5V (Note 1)
19	THV	HOLD High to Output Valid	30	—	ns	4.5V ≤ Vcc ≤ 5.5V
			60	—	ns	2.5V ≤ Vcc < 4.5V
			160	—	ns	1.8V ≤ Vcc < 2.5V
20	Twc	Internal Write Cycle Time	—	5	ms	(NOTE 3)
21	—	Endurance	1M	—	E/W Cycles	(NOTE 2)

Note 1: This parameter is periodically sampled and not 100% tested.

- 2:** This parameter is not tested but ensured by characterization. For endurance estimates in a specific application, please consult the Total Endurance™ Model which can be obtained from our web site: www.microchip.com.
- 3:** Twc begins on the rising edge of CS after a valid write sequence and ends when the internal write cycle is complete.

TABLE 1-3: AC TEST CONDITIONS

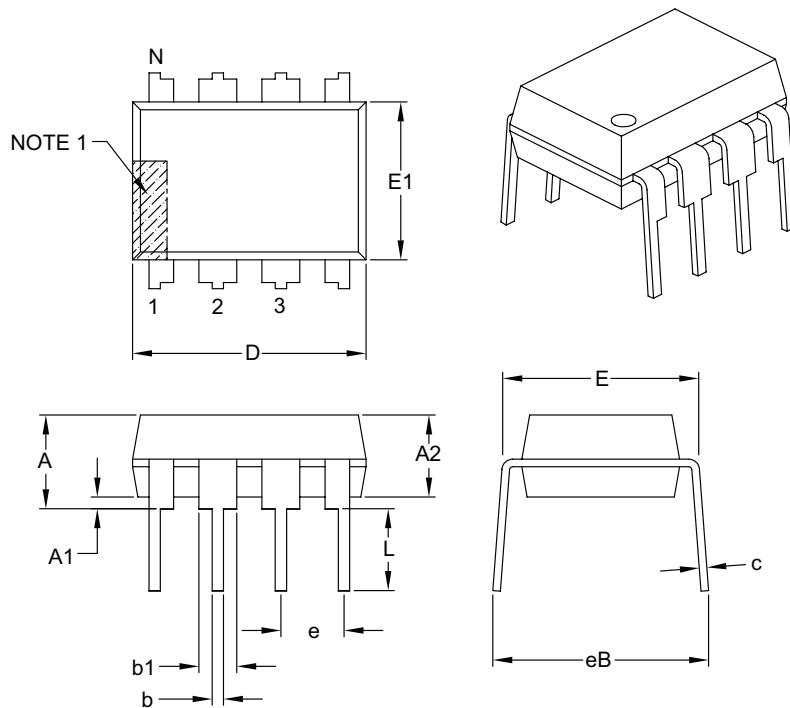
AC Waveform:	
VLO = 0.2V	—
VHI = VCC - 0.2V	(Note 1)
VHI = 4.0V	(Note 2)
Timing Measurement Reference Level	
Input	0.5 Vcc
Output	0.5 Vcc

Note 1: For VCC ≤ 4.0V

2: For VCC > 4.0V

25XX160A/B

8-Lead Plastic Dual In-Line (P) – 300 mil Body [PDIP]



Units		INCHES		
Dimension Limits		MIN	NOM	MAX
Number of Pins	N		8	
Pitch	e		.100 BSC	
Top to Seating Plane	A	—	—	.210
Molded Package Thickness	A2	.115	.130	.195
Base to Seating Plane	A1	.015	—	—
Shoulder to Shoulder Width	E	.290	.310	.325
Molded Package Width	E1	.240	.250	.280
Overall Length	D	.348	.365	.400
Tip to Seating Plane	L	.115	.130	.150
Lead Thickness	c	.008	.010	.015
Upper Lead Width	b1	.040	.060	.070
Lower Lead Width	b	.014	.018	.022
Overall Row Spacing §	eB	—	—	.430

Notes:

1. Pin 1 visual index feature may vary, but must be located with the hatched area.
2. § Significant Characteristic.
3. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" per side.
4. Dimensioning and tolerancing per ASME Y14.5M.

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing C04-018B

PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.

PART NO.	X	-	X	/XX	
Device	Tape & Reel		Temp Range	Package	
Device:					
25AA160A	16 Kbit, 1.8V, 16 Byte Page SPI Serial EEPROM				
25AA160B	16 Kbit, 1.8V, 32 Byte Page SPI Serial EEPROM				
25LC160A	16 Kbit, 2.5V, 16 Byte Page SPI Serial EEPROM				
25LC160B	16 Kbit, 2.5V, 32 Byte Page SPI Serial EEPROM				
Tape & Reel:					
Blank	=	Standard packaging			
T	=	Tape & Reel			
Temperature Range:					
I	=	-40°C to +85°C			
E	=	-40°C to +125°C			
Package:					
MS	=	Plastic MSOP (Micro Small Outline), 8-lead			
P	=	Plastic DIP (300 mil body), 8-lead			
SN	=	Plastic SOIC (3.90 mm body), 8-lead			
ST	=	TSSOP, 8-lead			

Examples:

- a) 25AA160A-I/MS = 16 Kbit, 16-byte page, 1.8V Serial EEPROM, Industrial temp., MSOP package
- b) 25AA160AT-I/SN = 16 Kbit, 16-byte page, 1.8V Serial EEPROM, Industrial temp., Tape & Reel, SOIC package
- c) 25LC160BT-I/SN = 16 Kbit, 32-byte page, 2.5V Serial EEPROM, Industrial temp., Tape & Reel, SOIC package
- d) 25LC160BT-I/ST = 16 Kbit, 32-byte page, 2.5V Serial EEPROM, Industrial temp., Tape & Reel, TSSOP package